

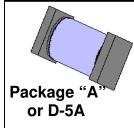
1N5614US thru 1N5622US

VOIDLESS-HERMETICALLY-SEALED SURFACE MOUNT STANDARD RECOVERY GLASS RECTIFIERS

DESCRIPTION

This "standard recovery" surface mount rectifier diode series is military qualified to MIL-PRF-19500/427 and is ideal for high-reliability applications where a failure cannot be tolerated. These industry-recognized 1.0 Amp rated rectifiers for working peak reverse voltages from 200 to 1000 volts are hermetically sealed with voidless-glass construction using an internal "Category I" metallurgical bond. These devices are also available in axial-leaded thru-hole package configurations (see separate data sheet for 1N5614 thru 1N5622). Microsemi also offers numerous other rectifier products to meet higher and lower current ratings with various recovery time speed requirements including fast and ultrafast device types in both through-hole and surface mount packages.

APPEARANCE



IMPORTANT: For the most current data, consult *MICROSEMI's* website: <u>http://www.microsemi.com</u>

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	FEATURES	APPLICATIONS / BENEFITS			
•	Surface mount package series equivalent to the JEDEC registered 1N5614 to 1N5622 series Voidless hermetically sealed glass package Triple-Layer Passivation Internal " <i>Category I</i> " Metallurgical bonds Working Peak Reverse Voltage 200 to 1000 Volts. JAN, JANTX, JANTXV, and JANS available per MIL- PRF-19500/427 Axial-leaded equivalents also available (see separate data sheet for 1N5614 thru 1N5622)	 Standard recovery 1 Amp rectifiers 200 to 1000 V Military and other high-reliability applications General rectifier applications including bridges, half- bridges, catch diodes, etc. High forward surge current capability Extremely robust construction Low thermal resistance Controlled avalanche with peak reverse power capability Inherently radiation hard as described in Microsemi MicroNote 050 			
	MAXIMUM RATINGS	MECHANICAL AND PACKAGING			
• • • • • •	Junction & Storage Temperature: -65° C to $+200^{\circ}$ C Thermal Resistance: 13° C/W junction to end cap Thermal Impedance: 4.5° C/W @ 10 ms heating time Average Rectified Forward Current (I ₀): 1.0 Amps @ T _A = 55° C and 0.75 Amps @ T _A = 100° C Forward Surge Current: 30 Amps @ 8.3 ms half-sine Solder Temperatures: 260° C for 10 s (maximum)	 CASE: Hermetically sealed voidless hard glass with Tungsten slugs TERMINALS: End caps are Copper with Tin/Lead (Sn/Pb) finish. Note: Previous inventory had solid Silver end caps with Tin/Lead (Sn/Pb) finish. MARKING & POLARITY: Cathode band only TAPE & REEL option: Standard per EIA-481-B WEIGHT: 193 mg See package dimensions and recommended pad layout on last page 			

ELECTRICAL CHARACTERISTICS

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ТҮРЕ	WORKING PEAK REVERSE	MINIMUM BREAKDOWN VOLTAGE	AVERAGE RECTIFIED CURRENT		FORWARD VOLTAGE (MAX.)	REVERSE CURRENT (MAX.)		MAXIMUM SURGE CURRENT	REVERSE RECOVERY (NOTE 3)
	VOLTAGE V _{RWM} V _{BR} @ 50μA I ₀ @ T _A V _F @ 3A (NOTE 1) (NOTE 1) (NOTE 1) (NOTE 1)		V _F @ 3A	I _R @ V _{RWM}		I _{FSM} (NOTE 2)	t _{rr}		
	VOLTS	VOLTS	AMPS		VOLTS	μΑ		AMPS	μs
			55°C	100°C		25°C	100°C		
1N5614US	200	220	1.00	.750		0.5	25	30	2.0
1N5616US	400	440	1.00	.750	0.8 MIN.	0.5	25	30	2.0
1N5618US	600	660	1.00	.750		0.5	25	30	2.0
1N5620US	800	880	1.00	.750	1.3 MAX.	0.5	25	30	2.0
1N5622US	1000	1100	1.00	.750		0.5	25	30	2.0

NOTE 1: From 1 Amp at $T_A = 55^{\circ}$ C, derate linearly at 5.56 mA/°C to 0.75 Amp at $T_A = 100^{\circ}$ C. From $T_A = 100^{\circ}$ C, derate linearly at 7.5 mA/°C to 0 Amps at $T_A = 200^{\circ}$ C. These ambient ratings are for PC boards where thermal resistance from mounting point to ambient is sufficiently controlled where $T_{J(max)}$ does not exceed 175 °C. **NOTE 2:** $T_A = 100^{\circ}$ C, f = 60 Hz, $I_O = 750$ mA for ten 8.3 ms surges @ 1 minute intervals **NOTE 3:** $I_F = 0.5A$, $I_{RM} = 1A$, $I_{R(REC)} = 0.250A$

Microsemi Scottsdale Division

www.Microsemi.com

8700 E. Thomas Rd. PO Box 1390, Scottsdale, AZ 85252 USA, (480) 941-6300, Fax: (480) 947-1503

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	SYMBOLS & DEFINITIONS		
Symbol	Definition		
V _{BR}	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.		
V _{RWM}	Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range.		
V _F	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.		
I _R	I _R Maximum Leakage Current: The maximum leakage current that will flow at the specified voltage and temperature.		
С	Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage		
t _{rr}	Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs.		

GRAPHS

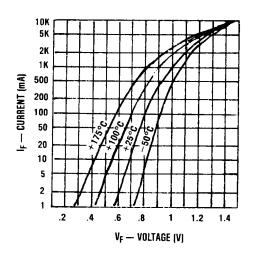


FIGURE 1 TYPICAL FORWARD VOLTAGE vs FORWARD CURRENT

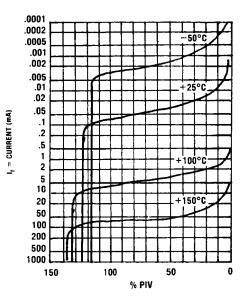
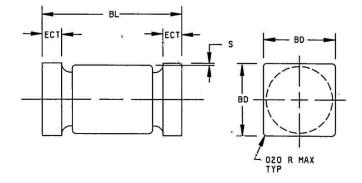


FIGURE 2 TYPICAL REVERSE CURRENT vs PIV



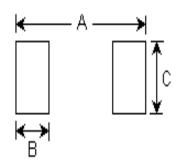
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PACKAGE DIMENSIONS AND PAD LAYOUT



NOTE: This Package Outline has also previously been identified as "D-5A"

	INC	HES	mm		
	MIN	MAX	MIN	MAX	
BD	.097	.103	2.46	2.62	
BL	.185	.200	4.70	5.08	
ECT	.019	.028	0.48	0.71	
S	.003		0.08		



PAD LAYOUT

	INCHES	mm		
Α	0.246	6.25		
В	0.067	1.70		
С	0.105	2.67		
Note: If mounting requires adhesive separate from the solder, an additional 0.060 inch diameter contact may be				

placed in the center between the pads as an optional spot for cement.